

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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GBU15J thru GBU15M

Silicon Bridge Rectifier

 $V_{RRM} = 50 \text{ V} - 1000 \text{ V}$ $I_F = 15 \text{ A}$

Features

 Plastic package has Underwriters Laboratory Flammability Classification 94V-0

 \bullet Types up to 1000 V V_{RRM}

· Ideal for printed circuit board

· High surge overload rating

• High temperature soldering guaranteed: 260°C/ 10 seconds, 0.375(9.5mm) lead length

· Glass passivated chip junction

 \bullet High case dielectric strength 1500 V_{RMS}

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GBU Package

Mechanical Data

Case: Molded plastic body over passivated junctions

Mounting position: Any

Terminals: Plated leads, solderable per MIL-STD-750

Method 2026 guaranteed

Maximum ratings, at $T_i = 25$ °C, unless otherwise specified

Parameter	Symbol	Conditions	GBU15J	GBU15K	GBU15M	Unit
Repetitive peak reverse voltage	V_{RRM}		600	800	1000	V
RMS reverse voltage	V_{RMS}		420	560	700	V
DC blocking voltage	V_{DC}		600	800	1000	V
Continuous forward current	I _F	T _C ≤ 100 °C	15	15	15	Α
Surge non-repetitive forward current, Half Sine Wave	I _{F,SM}	$T_C = 25 ^{\circ}\text{C}, t_p = 8.3 \text{ms}$	240	240	240	Α
Operating temperature	T _j		-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	T _{stg}		-55 to 150	-55 to 150	-55 to 150	°C

Electrical characteristics, at Tj = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	GBU15J	GBU15K	GBU15M	Unit
Diode forward voltage	V_{F}	I _F = 15 A, T _j = 25 °C	1.1	1.1	1.1	V
Reverse current	I _R	$V_R = 50 \text{ V}, T_j = 25 ^{\circ}\text{C}$	5	5	5	μA
		$V_R = 50 \text{ V}, T_j = 125 ^{\circ}\text{C}$	500	500	500	
Thermal characteristics						
Thermal resistance, junction - case	R_{thJC}		2.2	2.2	2.2	°C/W





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